QS3245

Q High-speed CMOS QuickSwitch Buffers

FEATURES/BENEFITS

- 5Ω switches connect inputs to outputs
- Pin compatible to the 74F245, 74FCT245, and 74FCT245T
- Low power CMOS proprietary technology
- Zero propagation delay
- TTL-compatible control inputs
- Zero ground bounce
- Available in 20-pin DIP, SOIC, and QSOP

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DESCRIPTION

The QS3245 provides a set of eight high-speed CMOS TTL-compatible bus switches in a pinout compatible with 74FCT245, 74F245, 74ALS/AS/LS245 8-bit transceivers. The low on resistance (5 ohms) of the 3245 allows inputs to be connected outputs without adding propagation delay and without generating additional ground bounce noise. The Output enable (/OE) signal turns the switches on similar to the /OE signal of the 74'245.

FUNCTIONAL BLOCK DIAGRAM





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3245 PINOUT



ALL PINS TOP VIEW

3245 PIN DESCRIPTION

Name	Description
ŌE	Output Enable
An	Data I/O's
Bn	Data I/O's

3245 FUNCTION TABLE

ŌĒ	OUTPUTS						
н	Disconnected						
L	An = Bn						

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ABSOLUTE MAXIMUM RATINGS

Supply Voltage to Ground	-0.5V to +7.0V
DC Switch Voltage V _S	-0.5V to +7.0V
DC Input Voltage VI	-0.5V to +7.0V
AC Input Voltage (for a pulse width 20 ns)	
DC Channel Current Max. current/pin	120 mA
Maximum Power Dissipation	0.5 watts
TSTGStorage Temperature	-65° to +165°C

CAPACITANCE

TA = 25 °C, f = 1 MHz, Vin = 0V, Vout = 0 V

Pins	SOIC		QSOP		PDIP		Unit
	Тур	Max	Тур	Max	Тур	Max	
Controls	3	4	3	4	4	5	рF
QuickSwitch Channels	7	8	7	8	8	9	

Note: Capacitance is characterized but not tested

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Symbol	Parameter	Test Conditions		Тур	Max	Unit
Vih	Input HIGH Voltage	Guaranteed Logic HIGH for Control Inputs	2.0	-	-	Volts
Vil	Input LOW Voltage	Guaranteed Logic LOW - for Control Inputs			0.8	Volts
l lin l	Input Leakage Current	0 ≤ Vin ≤ Vcc		-	5	μA
1 loz 1	Off State Current (Hi-Z)	$0 \le A, B \le Vcc$	-	-	5	μΑ
l los l	Short Circuit Current (2)	A (B) = 0V, B (A) = Vcc		300		mA
Ron	Switch On Resistance (Note 3)	Vcc = Min, Vin = 0.0 Volts Ion = 30 mA	-	5	7	Ω
		Vcc = Min, Vin = 2.4 Volts Ion = 15 mA	-	10	15	

Notes:

- Typical values indicate V_{CC}=5.0V and T_a=25°C.
 Not more than one output should be used to test this high power condition, and the duration is 1 second.
- Measured by voltage drop between A and B pin at indicated current through the switch. On resistance is deter-З. mined by the lower of the voltages on the two pins.
- 4. During input/output leakage testing all pins are at a High or Low state, and the OE control is High.

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POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions (1)	Min	Тур	Max	Unit
lcc	Quiescent Power Supply Current	Vcc = MAX, Vi = GND or Vcc, f = 0	-	-	2.5	mA
∆lcc	Pwr Supply Current, per Input High (2)	Vcc = MAX, Input = 3.4 V, f = 0 Per control input	-	-	3.5	mA
Qccd	Dynamic Pwr Supply Current per MHz (3)	Vcc = MAX, A & B pins open, Control input toggling @ 50% duty cycle	-	-	0.25	mA/ MHz

Notes:

- 1. For conditions shown as MIN or MAX use the appropriate values specified under DC specifications.
- Per TTL driven input (Vi=3.4V, control inputs only). A and B pins do not contribute to lcc. 2.
- Guaranteed by design. This current applies to the control inputs only and represents the current required to З. switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

Commercial $T_A = 0^\circ$ C to 70°C, Vcc = 5.0V±5% Military $T_A = -55^\circ$ C to 125° C, Vcc = 5.0V±10% Cload = 50 pF, Rload = 500 unless otherwise noted.

Symbol	Description	Note	Com		Mil		Unit
			Min	Max	Min	Max	1
t AB	Data Propagation Delay An to/from Bn	1,2,3		0.25		0.25	ns
t OEY	Swit <u>ch</u> Turn On Delay OE to An/Bn	1	0.5	5.6	0.5	6.6	ns
tPLZ tPHZ	Swit <u>ch</u> Turn Off Delay OE to An/Bn	1,2	0.5	4.5	0.5	5.5	ns

Notes:

- 1. See Test Circuit and Waveforms. Minimums guaranteed but not tested.
- This parameter is guaranteed by design but not tested. 2
- 3 The bus switch contributes no propagation delay other than the RC delay of the on resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25 ns for 50 pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch when used in a system is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

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